



NPN Darlington Power Silicon Transistor *Qualified per MIL-PRF-19500/539*

<u>Qualified Levels:</u> JAN, JANTX, and JANTXV

DESCRIPTION

This high speed NPN transistor is rated at 8 amps and is military qualified up to a JANTXV level. This TO-213AA isolated package features a 180 degree lead orientation.



TO-213AA (TO-66) Package

Important: For the latest information, visit our website http://www.microsemi.com.

FEATURES

- JEDEC registered 2N6300 and 2N6301
- Hermetically sealed
- JAN, JANTX, and JANTXV qualifications are available per MIL-PRF-19500/539
- RoHS compliant versions available (commercial grade only)

APPLICATIONS / BENEFITS

- Convenient package
- Mechanically rugged
- Military, space and other high reliability applications

MAXIMUM RATINGS @ T_C = 25 °C unless otherwise stated

| Parameters/Test Conditions | | Symbol | Value | Unit |
|--|---------------------------|---------------------|-------------|------|
| Junction and Storage Temperature | | T_J and T_{STG} | -55 to +200 | °C |
| Thermal Resistance Junction-to-Case | | R _{eJC} | 2.66 | °C |
| Collector-Base Voltage | 2N6300 | V _{CBO} | 60 | V |
| | 2N6301 | | 80 | |
| Collector-Emitter Voltage | 2N6300 | V_{CEO} | 60 | V |
| | 2N6301 | | 80 | |
| Emitter-Base Voltage | • | V_{EBO} | 5 | V |
| Continuous Operating Collector Current | | Ic | 8 | Α |
| Base Current | | I _B | 120 | mA |
| Total Power Dissipation (1) | @ T _C = 0 °C | P _T | 75 | W |
| | @ T _C = 100 °C | | 37 | |

NOTES: 1. Derate linearly at 0.428 W/ $^{\circ}$ C above T_C > 0 $^{\circ}$ C.

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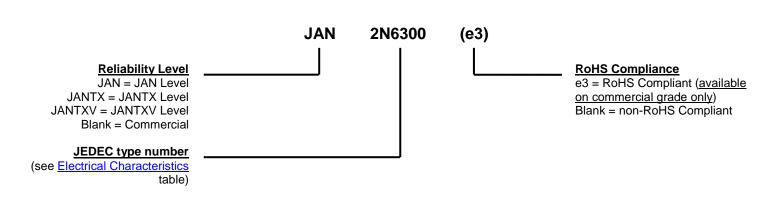
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MECHANICAL and PACKAGING

- CASE: Hermetic, TO-213AA package. Nickel plate with nickel cap.
- TERMINALS: Solder dipped (Sn63/Pb37) over nickel plated alloy 52. RoHS compliant matte-tin plating is also available on commercial grade only.
- MARKING: MSC, part number, date code, polarity symbol
- WEIGHT: Approximately 5.7 grams
- See Package Dimensions on last page.

PART NOMENCLATURE



| SYMBOLS & DEFINITIONS | | | | | | |
|-----------------------|---|--|--|--|--|--|
| Symbol | Definition | | | | | |
| I _B | Base current: The value of the dc current into the base terminal. | | | | | |
| Ic | Collector current: The value of the dc current into the collector terminal. | | | | | |
| Ι _Ε | Emitter current: The value of the dc current into the emitter terminal. | | | | | |
| T _C | Case temperature: The temperature measured at a specified location on the case of a device. | | | | | |
| V_{CB} | Collector-base voltage: The dc voltage between the collector and the base. | | | | | |
| V _{CBO} | Collector-base voltage, base open: The voltage between the collector and base terminals when the emitter terminal is open-circuited. | | | | | |
| V_{CC} | Collector-supply voltage: The supply voltage applied to a circuit connected to the collector. | | | | | |
| V_{CE} | Collector-emitter voltage: The dc voltage between the collector and the emitter. | | | | | |
| V _{CEO} | Collector-emitter voltage, base open: The voltage between the collector and the emitter terminals when the base terminal is open-circuited. | | | | | |
| V_{EB} | Emitter-base voltage: The dc voltage between the emitter and the base | | | | | |
| V_{EBO} | Emitter-base voltage, collector open: The voltage between the emitter and base terminals with the collector terminal open-circuited. | | | | | |



ELECTRICAL CHARACTERISTICS @ 25 °C unless otherwise stated

| Parameters / Test Conditions | | Symbol | Min. | Max. | Unit |
|---|------------------|----------------------|-------------------|------------|------|
| ON CHARACTERISTICS | | | | | |
| Collector-Emitter Breakdown Voltage I _C = 100 mA | 2N6300 2N6301 | V _{(BR)CEO} | 60 80 | | V |
| Collector-Emitter Cutoff Current $V_{CE} = 60 V_{BE} = 1.5 V$ $V_{CE} = 80 V_{BE} = 1.5 V$ | 2N6300 2N6301 | I _{CEX} | | 10 | μΑ |
| Collector-Emitter Cutoff Current, Base Open $V_{CE} = 30 \text{ V}$ $V_{CE} = 40 \text{ V}$ | 2N6300 2N6301 | I _{CEO} | | 0.5 | mA |
| Emitter-Base Cutoff Current $V_{EB} = 5 \text{ V}$ | | I _{EBO} | | 2.0 | mA |
| Forward Current Transfer Ratio $I_C = 1 \text{ A}$, $V_{CE} = 3 \text{ V}$ $I_C = 4 \text{ A}$, $V_{CE} = 3 \text{ V}$ $I_C = 8 \text{ A}$, $V_{CE} = 3 \text{ V}$ | | h _{FE} | 500 750 100 | 18000 | |
| Collector-Emitter Saturation Voltage $I_C = 4.0 \text{ A}, I_B = 16 \text{ mA}$ $I_C = 8.0 \text{ A}, I_B = 80 \text{ mA}$ | | V _{CE(sat)} | | 2.0 3.0 | V |
| Base-Emitter Saturation Voltage $V_{CE} = 3.0 \text{ V}, I_{C} = 4 \text{ A}$ $I_{C} = 8.0 \text{ A}, I_{B} = 80 \text{ mA}$ | | V _{BE(sat)} | | 2.8 4.0 | V |

DYNAMIC CHARACTERISTICS

| Parameters / Test Conditions | Symbol | Min. | Max. | Unit |
|--|-----------------|------|------|------|
| Magnitude of Common Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio $V_{CE} = 3.0 \text{ V}, I_{C} = 3.0 \text{ A}, f = 1 \text{ MHz}$ | h _{fe} | 25 | 350 | |
| Common Emitter Small-Signal Short-Circuit Forward Current Trans-Ratio V _{CE} = 3 V, I _C = 3 A, f = 1 kHz | h _{fe} | 300 | | |
| Common Base Output $V_{CB} = 10 \text{ V}, I_E = 0 \text{ A}, 100 \text{ kHz} \le f \le 1 \text{ MHz}$ | C_{obo} | | 200 | pF |



ELECTRICAL CHARACTERISTICS @ T_C = 25 °C unless otherwise noted. (continued)

SWITCHING CHARACTERISTICS

| Parameters / Test Conditions | Symbol | Min. | Max. | Unit |
|--|------------------|------|------|------|
| Turn-On time $V_{CC} = 30 \text{ V}, I_C = 4 \text{ A}, I_{B1} = 16 \text{ mA}$ | t _{on} | | 2.0 | μS |
| Turn-Off time $V_{CC} = 30 \text{ V}, I_C = 4 \text{ A}, I_{B1} = -I_{B2} = 16 \text{ mA}$ | t _{off} | | 8.0 | μS |

SAFE OPERATING AREA (See Figures 1 and 2 and MIL-STD-750, Test Method 3053)

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DC Tests
T_{C} = +25 \, ^{\circ}\text{C}, \, t = 1 \, \text{second, duty cycle} \leq 10\%
Test 1
V_{CE} = 8 \, \text{V}, \, I_{C} = 8 \, \text{A}
Test 2
V_{CE} = 20 \, \text{V}, \, I_{C} = 2.0 \, \text{A}
Test 3
V_{CE} = 60 \, \text{V}, \, I_{C} = 100 \, \text{mA} \, (2\text{N}6300)
V_{CE} = 80 \, \text{V}, \, I_{C} = 100 \, \text{mA} \, (2\text{N}6301)
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SAFE OPERATING AREA

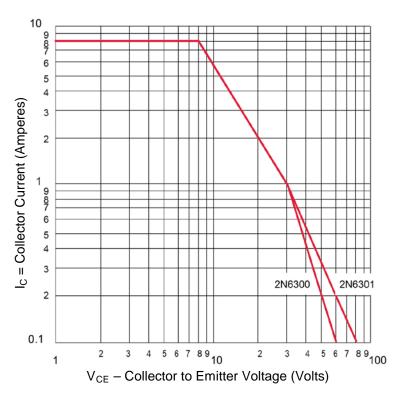


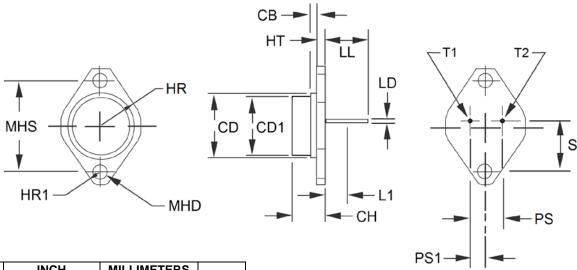
FIGURE 1 - Maximum Safe Operating Area (dc)



FIGURE 2 – Safe Operating Area for switching between saturation and cutoff (unclamped inductive load)



PACKAGE DIMENSIONS



| DIM | INCH | | MILLIMETERS | | |
|------|-----------|-------|-------------|-----------|-------|
| DIN | MIN | MAX | MIN | MAX | Notes |
| СВ | 0.470 | 0.500 | 11.94 | 12.70 | |
| CD | - | 0.620 | - | 15.76 | |
| CH | 0.250 | 0.340 | 6.35 | 8.64 | |
| HR | - | 0.350 | - | 8.89 | |
| HT | 0.050 | 0.075 | 1.27 | 1.91 | |
| HR1 | 0.115 | 0.145 | 2.92 | 3.68 | 4 |
| LD | 0.028 | 0.034 | 0.71 | 0.86 | 4, 6 |
| LL | 0.360 | 0.500 | 9.14 | 12.70 | |
| L1 | 1 | 0.050 | - | 1.27 | 6 |
| MHD | 0.142 | 0.152 | 3.61 | 3.61 3.86 | |
| MHS | 0.958 | 0.962 | 24.33 | 24.43 | |
| PS | 0.190 | 0.210 | 4.83 | 5.33 | 3 |
| PS1 | 0.093 | 0.107 | 2.36 | 2.73 | 3 |
| S | 0.570 | 0.590 | 14.48 | 14.99 | |
| T1 | Base | | | | |
| T2 | Emitter | | | | |
| Case | Collector | | | | |

NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for information only.
- These dimensions should be measured at points 0.050 inch (1.27 mm) +0.005 inch (0.13 mm) -0.000 inch (0.00 mm) below seating plane.
 When gauge is not used, measurement will be made at the seating plane.
- 4. Two places.
- The seating plane of the header shall be flat within 0.001 inch (0.03 mm) concave to 0.004 inch (0.10 mm) convex inside a 0.930 inch (23.62 mm) diameter circle on the center of the header and flat within 0.001 inch (0.03 mm) concave to 0.006 inch (0.15 mm) convex overall.
- 6. Lead diameter shall not exceed twice LD within L1.
- 7. Lead number 1 is the emitter, lead 2 is the base, case is the collector.
- 8. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

SCHEMATIC

